

*Preliminary Specifications Subject to Change without Notice*

## DESCRIPTION

JW<sup>®</sup>77216 is a synchronous rectifier, used for the secondary side rectification of isolation topologies, such as Active Clamp Flyback and CCM/QR/DCM Flyback. JW77216 is able to significantly improve the efficiency comparing with the conventional Diode rectifier.

When JW77216 senses  $V_{ds}$  of MOSFET less than -140mV, it turns on the internal MOSFET. Once the  $V_{ds}$  is greater than -3mV, JW77216 turns off the internal MOSFET.

JW77216 supports multiple operation modes, such as DCM, CrCM, CCM and Quasi-Resonant. By implementing the Joulwatt proprietary technology, JW77216 is able to handle CCM operation.

JW77216 is available in SOP-8 package.

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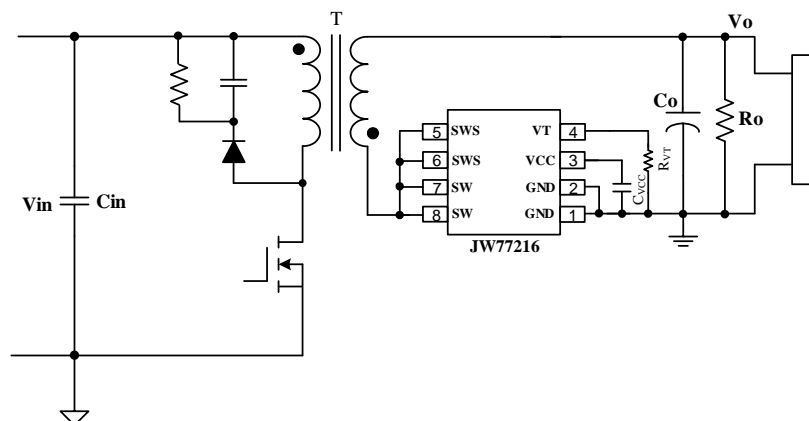
## FEATURES

- Supports Active Clamp Flyback, DCM, Quasi-Resonant, and CCM Flyback
- Support High-side and Low-side Rectification
- Output Voltage Directly Supply VCC
- Low Quiescent Current
- Fast Driver Capability for CCM Operation
- SOP-8 Package

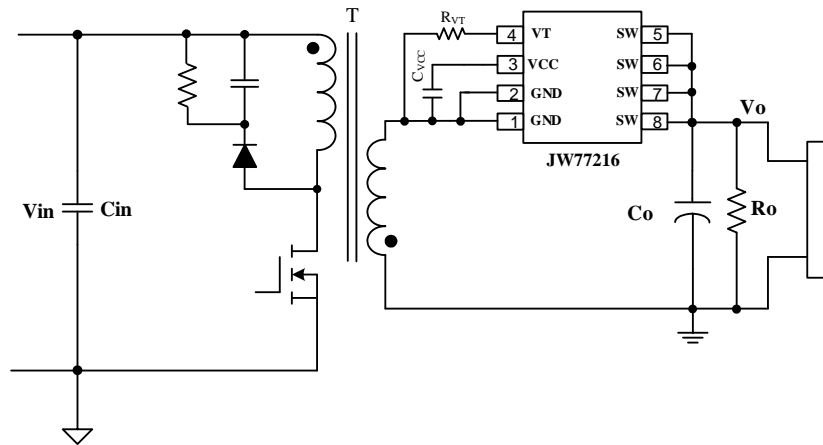
## APPLICATIONS

- Active Clamp Flyback and Flyback Converters
- Adaptor
- LCD and PDP TV

## TYPICAL APPLICATION



**JW77216 Typical Application for Low-side**

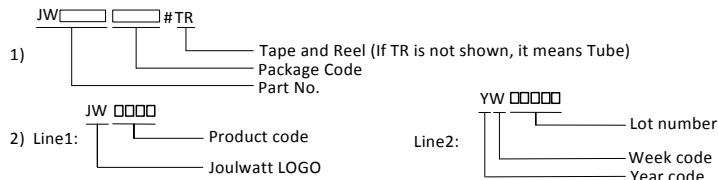


**JW77216 Typical Application for High-side.**

## ORDER INFORMATION

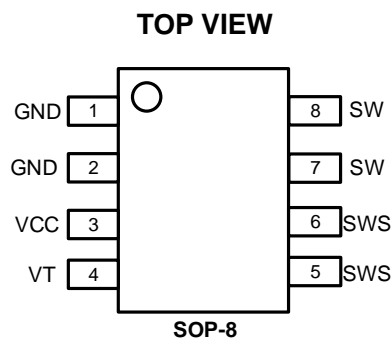
DEVICE <sup>1)</sup>	PACKAGE	TOP MARKING <sup>2)</sup>	ENVIRONMENTAL <sup>3)</sup>
JW77216SOPB#TR	SOP8	JW77216 YW□□□□□	Green

## Notes:



3) All Joulwatt products are packaged with Pb-free and Halogen-free materials and compliant to RoHS standards.

## PIN CONFIGURATION

ABSOLUTE MAXIMUM RATING<sup>1)</sup>

SW PIN .....	-1 to 140V
VO PIN .....	-0.3 to 28V
VCC PIN.....	-0.3 to 8.7V
VT PIN.....	-0.3 to 7V
Junction Temperature <sup>2) 3)</sup> .....	150°C
Lead Temperature .....	260°C
Storage Temperature.....	-65°C to150°C
Continuous Power Dissipation( $T_A=+25^{\circ}\text{C}$ ) <sup>4)</sup> SOP-8.....	1.04W
ESD Susceptibility (Human Body Model) .....	2kV
MSL (Moisture-Sensitive Level) .....	MSL 3

RECOMMENDED OPERATING CONDITIONS

SW Pin.....	4.7V to 48V
VT Pin.....	0V to 5V
VCC PIN.....	4V to 8.5V
Operation Junction Temperature.....	-40°C to 125°C

THERMAL PERFORMANCE<sup>5)</sup>

$\theta_{JA}$     $\theta_{JC}$

SOP-8.....	120.....60°C/W
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Note:

- 1) Exceeding these ratings may damage the device. These stress rating do not imply function operation of the device at any other conditions beyond those indicated under RECOMMENDED OPERATING CONDITIONS.
- 2) Continuous operation over the specified absolute maximum operating junction temperature may damage the device.
- 3) The device is not guaranteed to function outside of its operating conditions.
- 4) The maximum allowable continuous power dissipation at any ambient temperature is calculated by  $P_D(MAX)=(T_J(MAX)-T_A)/ \theta_{JA}$ .
- 5) Measured on JESD51-7, 4-layer PCB

## ELECTRICAL CHARACTERISTICS

*TA = 25°C, unless otherwise stated*

Item	Symbol	Condition	Min.	Typ.	Max.	Units
<i>VCC Section</i>						
VCC Voltage	VCC	SW=40V, VCC=2.2uF		8		V
VCC Startup Voltage	V <sub>CC_Startup</sub>	VCC Rising		4.5		V
VCC Startup Voltage Hysteresis				0.5		V
Operation Current (GT On)	I <sub>VCC</sub>	GT=5nF, VCC=2.2uF		0.9		mA
Quiescent Current	I <sub>q</sub>	VCC=4.5V, VCC=2.2uF		110		uA
<i>SW and VO Section</i>						
Internal MOS Turn on Threshold	V <sub>MOS_ON</sub>			-140		mV
Internal MOS Turn off Threshold	V <sub>MOS_OFF</sub>			-3		mV
Internal MOS Minimum on Time	T <sub>MIN_ON</sub>			1.1		uS
Turn-on Total Delay	T <sub>DON</sub>	<sup>6)</sup>		50		nS
Turn-off Total Delay	T <sub>DOF</sub>	<sup>6)</sup>		20		nS
VCC Charge Current	I <sub>SW_CHG</sub>	SW=40V, VCC=6V		85		mA
<i>Internal MOSFET Section</i>						
Internal MOSFET Rdson	Rdson	VGT=10V		10		mΩ
Breakdown Voltage	B <sub>(BR)DSS</sub>		60			V

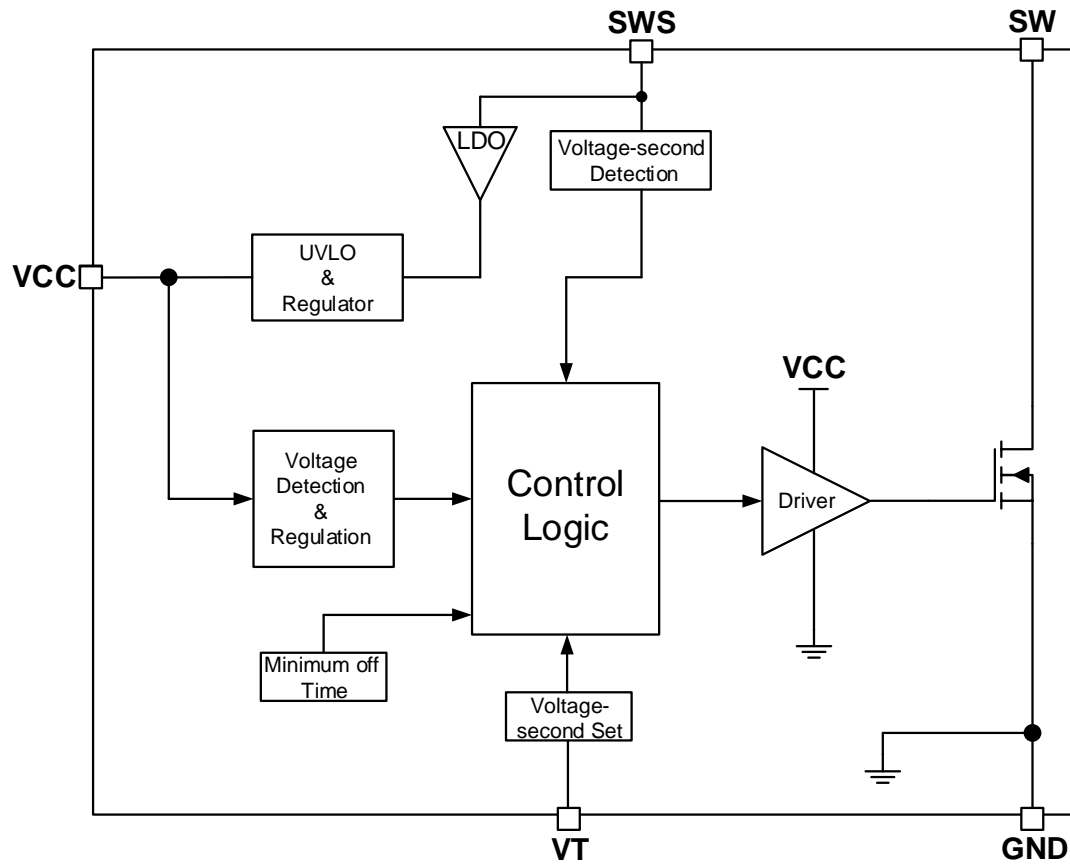
**Note:**

6) Guaranteed by design.

## PIN DESCRIPTION

Pin	Name	Description
1,2	GND	Ground.
3	VCC	Power supply. Bypass a Capacitor Between VCC and GND.
4	VT	Set the voltage-second product.
5,6	SWS	Internal Power MOSFET Drain Voltage Sensing. Charging to VCC.
7,8	SW	Internal Power MOSFET Drain.

## BLOCK DIAGRAM



## FUNCTIONAL DESCRIPTION

### Operation

JW77216 is a synchronous rectifier combined with internal MOSFET can replace the Schottky Barrier Diode. It supports all operations, such as DCM, CrCM, (Quasi-Resonant) and CCM when adopted in Active Clamp Flyback and Flyback converters.

### Startup

During the startup period, when the VCC is charged up by the two internal LDOs connected to SW and VO pin respectively.

A capacitor between VCC and GND is required to store the energy and supply to IC during the SR turn-on period.

Once the VCC voltage exceeds  $V_{CC\_Startup}$ , the JW77216 exits the UVLO. If VCC is lower than  $V_{CC\_UVLO}$  ( $V_{CC\_Startup}-0.5V$ ), the internal MOSFET is turned off. The current flows through body diode before the VCC reaches to the startup voltage  $V_{cc\_startup}$ .

### Under-Voltage Lockout (UVLO)

When the VCC is below UVLO( $V_{CC\_Startup}-0.5V$ ) threshold, the internal MOSFET is turned off and pulled low internally. Once the VCC exceeds the startup voltage  $V_{cc\_startup}$ , the parts is activated again.

### Turn On Phase

There are two conditions for the JW77216 to turn on the internal MOSFET, i.e.  $V_{sw}$ , voltage-second value on SW pin when primary side switch is on, and the turn on phase is shown in Figure. 1.

1)  $V_{sw}$ : when the synchronous MOSFET is

conducting, current flows through the body diode of MOSFET, which generates a negative voltage  $V_{SW}$  across it. When  $V_{SW}$  is lower than  $V_{MOS\_ON}$ , the part will pull the gate high to turn on the synchronous MOSFET after turn on delay time  $T_{DON}$  if the other condition is met.

2) Volt-second of SW: in DCM and QR operation, there are parasitic oscillations. In some applications, the drain resonant voltage may fall below the SR turn on threshold, especially for the first couple rings. SR could be falsely turned on, which may cause shoot through issue and result in high power loss. The volt-second value of SW pin can be used to distinguish the parasitic ring from normal primary side switch on. The threshold can be set by the resistance at VT pin. The curve is shown in Figure. 2.

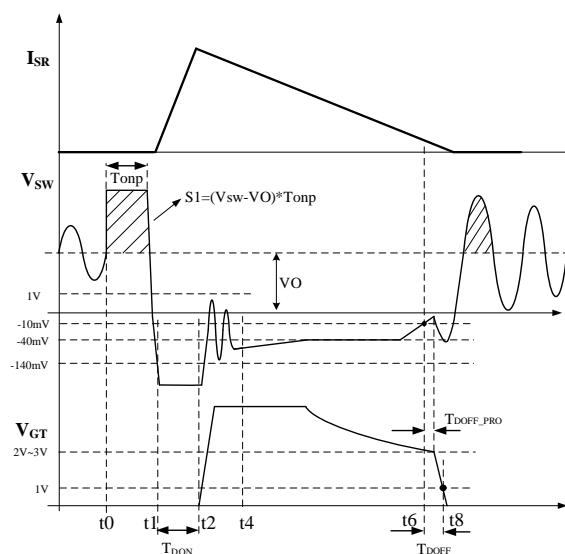
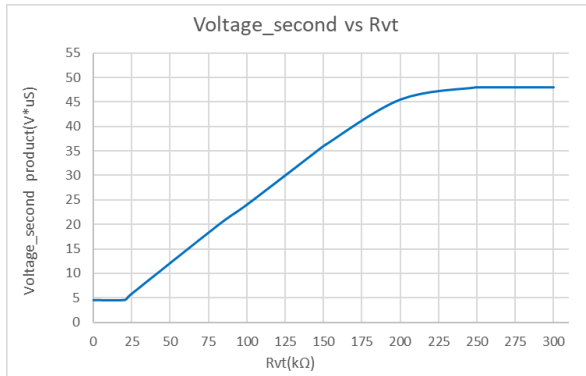


Figure. 1 Turn on delay and turn off delay





**Figure-2 Volt-second value vs. VT resistance**

### Minimum On Time (MOT)

When the synchronous MOSFET is turn on, there is a minimum on time for the SR. The  $V_{SW}$  voltage may have a parasitic ring when the synchronous MOSFET turns on. So, a minimum on time (MOT) is very important to avoid the MOSFET turn off threshold is false triggered. Minimum on time is about 1.1us.

### Conducting Phase

When the synchronous MOSFET is turned on, the drain source voltage  $V_{SW}$  it is determined by its on resistance and the current through it. The part adjusts the gate voltage and regulates the

$V_{sw}$  to the internal threshold (typical -40mV) after the synchronous MOSFET turn on. When the  $V_{SW}$  is lower than -40mV, the gate keeps its maximum voltage. And the synchronous MOSFET is fully on.

The  $V_{SW}$  rises when the current follow through the MOSFET decreases. The gate voltage will be decreased to increase its on resistance and regulate the  $V_{SW}$  around -40mV.

It should be noted that the typical regulation threshold (typical -40mV) during MOSFET on time is not fixed, it can be internally changed to ensure the proper operation under CCM mode.

### Turn Off Phase

After synchronous MOSFET conducting, once the voltage  $V_{SW}$  touches the MOSFET turn off threshold, the gate is pulled to low after a turn off delay time  $T_{DOFF}$ . A 365nS blanking time is necessary to avoid error trigger. The banking time is reset once  $V_{sw}$  rises above +2.5V.

PACKAGE OUTLINE

SOP8

Unit: mm

Symbol	MILLIMETER		
	MIN	NOM	MAX
A	—	—	1.75
A1	0.05	0.15	0.25
A2	1.25	1.40	1.65
b	0.32	0.42	0.52
c	0.10	0.20	0.30
D	4.50	5.00	5.50
E	5.50	6.00	6.50
E1	3.50	3.90	4.30
e	1.27TYP		
L	0.40	—	1.27
θ	0°	—	8°

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPAE

Sprocket Holes

Sprocket Quadrants

Package Type	Pin1 Quadrant
SOP8	1

## IMPORTANT NOTICE

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